

RJK0853DPB

80V, 40A, 8.0m Ω max. Silicon N Channel Power MOS FET Power Switching

R07DS0081EJ0300 Rev.3.00 Apr 09, 2013

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting

Low on-resistance

 $R_{DS(on)} = 6.2 \text{ m}\Omega \text{ typ. (at } V_{GS} = 10 \text{ V})$

- Pb-free
- Halogen-free

Outline

RENESAS Package code: PTZZ0005DA-A (Package name: LFPAK)

1, 2, 3 Source
4 Gate
5 Drain

Application

• Switching Mode Power Supply

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	80	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I _D	40	A
Drain peak current	I _{D(pulse)} Note1	160	A
Body-drain diode reverse drain current	I _{DR}	40	A
Avalanche current	I _{AP} Note 2	20	A
Avalanche energy	E _{AS} Note 2	53.3	mJ
Channel dissipation	Pch Note3	65	W
Channel to Case Thermal Resistance	θch-C	1.92	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. Tc = 25°C

This product is for the low voltage drive ($\leq 10V$).

If the driving voltage is over 10 V under normal conditions, please use the product for high gate to source cutoff voltage $(V_{GS(off)})$ which characteristics has been improved.

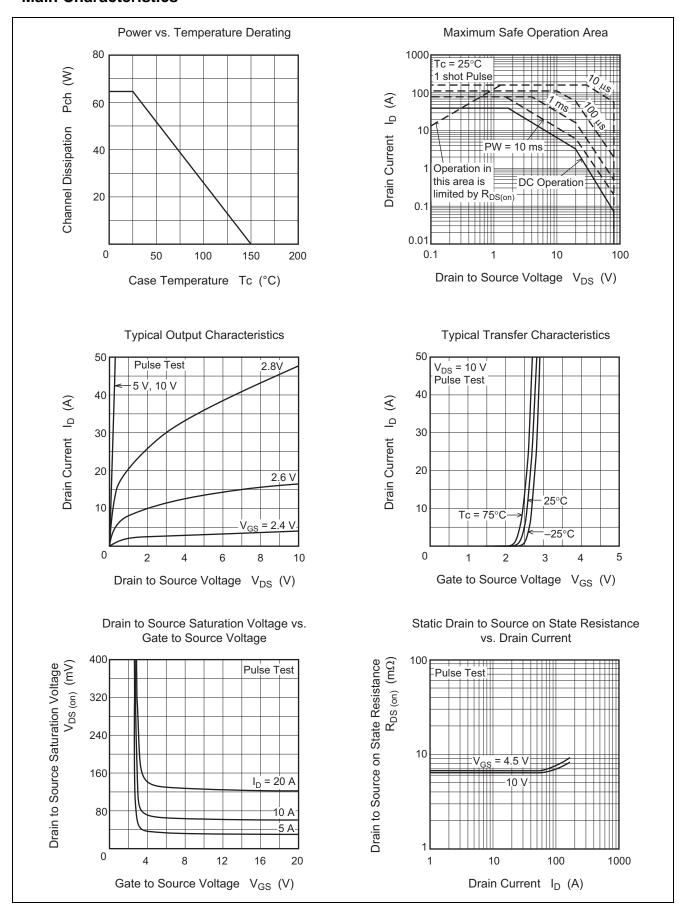
Electrical Characteristics

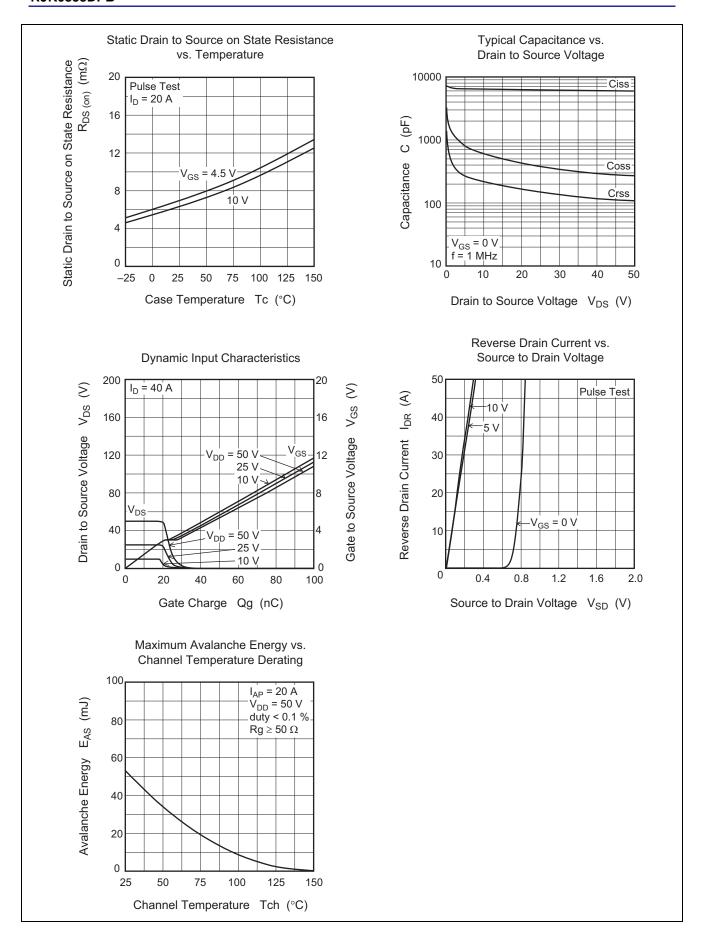
 $(Ta = 25^{\circ}C)$

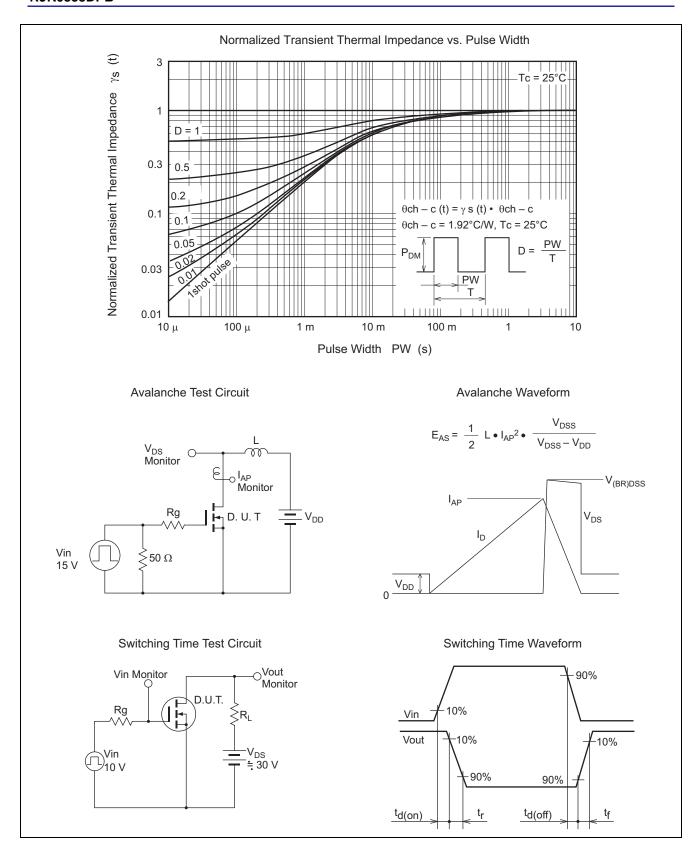
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	80	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$
Gate to source leak current	I_{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$
Zero gate voltage drain current	I _{DSS}	1	_	1	μΑ	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	6.2	8.0	mΩ	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	6.7	9.2	mΩ	$I_D = 20 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	_	100	_	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss		6170	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$
Output capacitance	Coss		600	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss		235	_	pF	
Gate Resistance	Rg		0.5	_	Ω	
Total gate charge	Qg	_	40	_	nC	$V_{DD} = 25 \text{ V}, V_{GS} = 4.5 \text{ V},$
Gate to source charge	Qgs	_	19	_	nC	I _D = 40 A
Gate to drain charge	Qgd	_	11	_	nC	
Turn-on delay time	t _{d(on)}	_	14	_	ns	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A},$
Rise time	t _r	_	7.2	_	ns	$V_{DD} \cong 30 \text{ V}, \text{ R}_{L} = 1.5 \ \Omega,$ $\text{Rg} = 4.7 \ \Omega$
Turn-off delay time	t _{d(off)}		70	_	ns	
Fall time	t _f		12	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.82	1.1	V	$I_F = 40 \text{ A}, V_{GS} = 0 \text{ V}^{\text{Note4}}$
Body–drain diode reverse recovery time	t _{rr}	_	42	_	ns	$I_F = 40 \text{ A}, V_{GS} = 0 \text{ V},$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

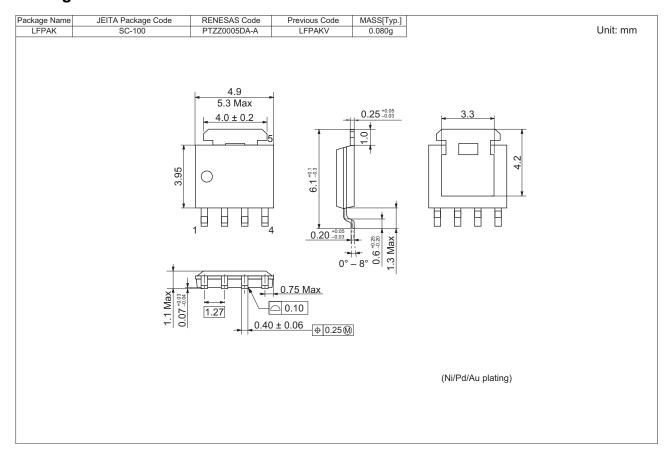
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK0853DPB-00-J5	2500 pcs	Taping

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